

# UNISONIC TECHNOLOGIES CO., LTD

UD4P20 Preliminary Power MOSFET

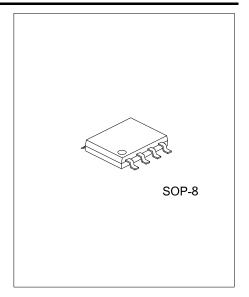
# 4A, 20V DUAL P-CHANNEL POWER MOSFET

#### ■ DESCRIPTION

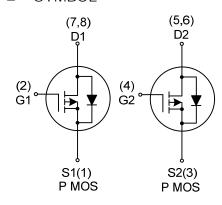
The UTC **UD4P20** uses advanced technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with low gate voltages. This device is manufacturing reproducible. The UTC **UD4P20** is suitable for applications, such as battery management in nomadic equipment and power management in cellular phone.

#### ■ FEATURES

- \*  $R_{DS(ON)}$ : 0.07 $\Omega$  (TYP.)
- \* Low on-resistance
- \* Rugged avalanche characteristic
- \* Easy automated surface mount assembly with standard outline
- \* Low threshold drive



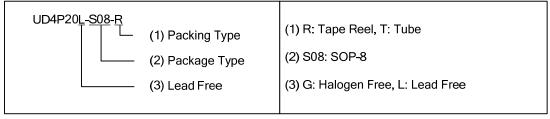
#### ■ SYMBOL



### ORDERING INFORMATION

Ordering Number		Dookone	Dealine	
Lead Free	Halogen Free	Package	Packing	
UD4P20L-S08-R	UD4P20G-S08-R	SOP-8	Tape Reel	
UD4P20L-S08-T	UD4P20G-S08-T	SOP-8	Tube	

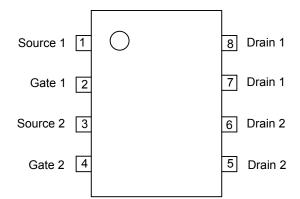
Note: Pin Assignment: G: Gate D: Drain S: Source



www.unisonic.com.tw 1 of 4

# ■ PIN CONFIGURATION

**UD4P20** 



## ■ ABSOLUTE MAXIMUM RATINGS (unless otherwise specified.)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage (V <sub>GS</sub> =0V)		$V_{DSS}$	-20	V
Drain-Gate Voltage (R <sub>GS</sub> = 20)	kΩ)	$V_{DGR}$	-20	V
Gate-Source Voltage		$V_{GSS}$	±16	V
Continuous Drain Current		I <sub>D</sub>	-4	Α
Continuous Drain Current (T <sub>C</sub> =25°C, Single Operation) Pulsed Drain Current (Note 2)				
Pulsed Drain Current (Note 2)		$I_{DM}$	-16	Α
Power Dissipation (T <sub>C</sub> =25°C)	Dual Operation	P <sub>D</sub>	1.6	W
	Single Operation		2	W
Junction Temperature		ΤJ	+150	°C
Storage Temperature		$T_{STG}$	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### ■ THERMAL DATA

PARAMETE	₹	SYMBOL	RATINGS	UNIT
Landa Andrian	Single Operation	θја	62.5	°C/W
Junction to Ambient	Dual Operation		78	°C/W

Note: When Mounted on 0.5 in<sup>2</sup> pad of 2oz. copper

# ■ ELECTRICAL CHARACTERISTICS (T<sub>C</sub> =25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D = -250 \mu A, V_{GS} = 0 V$	-20			V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20 V, V <sub>GS</sub> =0 V			-1	μΑ
Gate- Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
ON CHARACTERISTICS (Note 1)						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-1	-1.6	-2.5	V
Static Drain-Source On-State Resistance		V <sub>GS</sub> =-10 V, I <sub>D</sub> =-2A		70	80	mΩ
	$R_{DS(ON)}$	$V_{GS} = -4.5 \text{ V}, I_D = -2A$		85	100	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	C <sub>ISS</sub>	051/1/		1350		pF
Output Capacitance	Coss	V <sub>DS</sub> =-25 V, V <sub>GS</sub> =0 V		490		pF
Reverse Transfer Capacitance	$C_{RSS}$	f=1MHz		130		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	$t_{D(ON)}$			25		ns
Turn-ON Rise Time	t <sub>R</sub>	$V_{DD}$ =-15V, $I_{D}$ =-2A , $V_{GS}$ =-4.5 V, $R_{G}$ =4.7 $\Omega$		35		ns
Turn-OFF Delay Time	t <sub>D(OFF)</sub>			125		ns
Turn-OFF Fall-Time	t <sub>F</sub>			35		ns
Total Gate Charge	$Q_{G}$			12.5	16	nC
Gate Source Charge	Q <sub>GS</sub>	$V_{DD} = -24 \text{ V}, V_{GS} = -5 \text{ V}$ $I_{D} = -4 \text{ A}$		5		nC
Gate Drain Charge	$Q_{GD}$			3		nC
SOURCE- DRAIN DIODE RATINGS AND CHA	ARACTERIST	ics				
Drain-Source Diode Forward Voltage (Note 1)	$V_{SD}$	I <sub>SD</sub> =-4 A, V <sub>GS</sub> =0 V			-1.2	V
Maximum Continuous Drain-Source Diode	,				4	^
Forward Current	$I_{SD}$				-4	Α
Maximum Pulsed Drain-Source Diode	1				-16	Α
Forward Current (Note 2)	I <sub>SDM</sub>				-10	А
Reverse Recovery Time	t <sub>rr</sub>	I <sub>SD</sub> =-4A, V <sub>DD</sub> =-15V		45		ns
Reverse Recovery Charge	$Q_RR$	dI/dt =100A/μs, T <sub>J</sub> =150°C		36		nC

Notes: 1. Pulsed: Pulse duration =300µS, duty cycle≤1.5 %.

<sup>2.</sup> Pulse width limited by safe operating area.



<sup>2.</sup> Pulse width limited by safe operating area.

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.